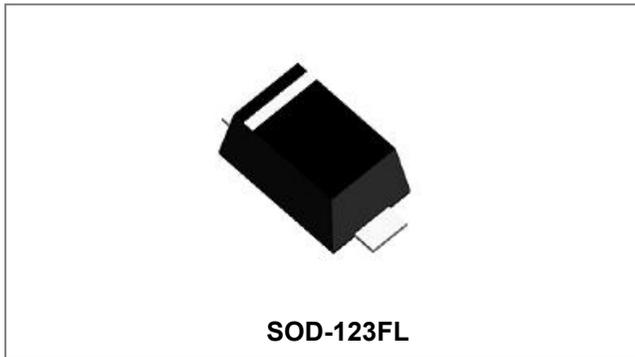


**DSS22U THRU DSS220U**  
**SINGLE PHASE 2.0AMP SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER**



**Features**

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High temperature soldering guaranteed: 260/10° C seconds, 0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

**Circuit Diagram**



**Mechanical Data**

- Case: SOD-123FL, molded plastic
- Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band dented cathode end
- Mounting Position: Any

**Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified**

Characteristic	Symbol	DSS 22U	DSS 23U	DSS 24U	DSS 25U	DSS 26U	DSS 28U	DSS 210U	DSS 215U	DSS 220U	Units	
	Marking Code	D22U	D23U	D24U	D25U	D26U	D28U	D210U	D215U	D220U		
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	V	
DC Blocking Voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	V	
RMS Reverse Voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	V	
Average Rectified Output Current at T <sub>L</sub> =90°C	I <sub>F(AV)</sub>	2.0									A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on Rated load(JEDEC Method)	I <sub>FSM</sub>	60									A	
I <sup>2</sup> t Rating for Fusing (t < 8.3ms)	I <sup>2</sup> t	14.94									A <sup>2</sup> s	
Forward Voltage per element @I <sub>F</sub> =2.0A	V <sub>F</sub>	0.50			0.67		0.80	0.90			V	
Peak Reverse Current T <sub>A</sub> =25 °C at rated DC blocking voltage T <sub>A</sub> =100 °C	I <sub>R</sub>	0.1					0.05					mA
		10					5					
Typical Junction Capacitance (Note 1)	C <sub>J</sub>	100					50					pF
Typical Thermal Resistance Junction to Ambient (Note 2)	R <sub>θJA</sub>	75									°C/W	
Junction and Storage Temperature Range	T <sub>J</sub>	-55 to +150									°C	
Junction and Storage Temperature Range	T <sub>STG</sub>	-55 to +150									°C	

Note: 1. Measured at 1MHz and applied reverse voltage of 4V D.C  
2. PCB mounted on 0.2 X 0.2" (5.0 X 5.0 mm) copper pad areas.

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - [sales@smc-diodes.com](mailto:sales@smc-diodes.com) •

**Ratings and Characteristics Curves**

FIG. 1- FORWARD CURRENT DERATING CURVE

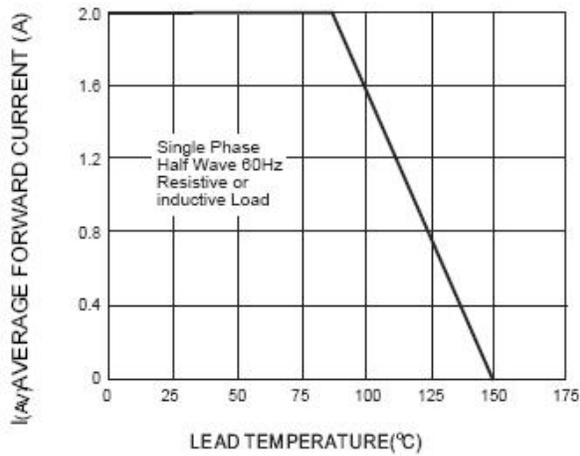


FIG. 2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

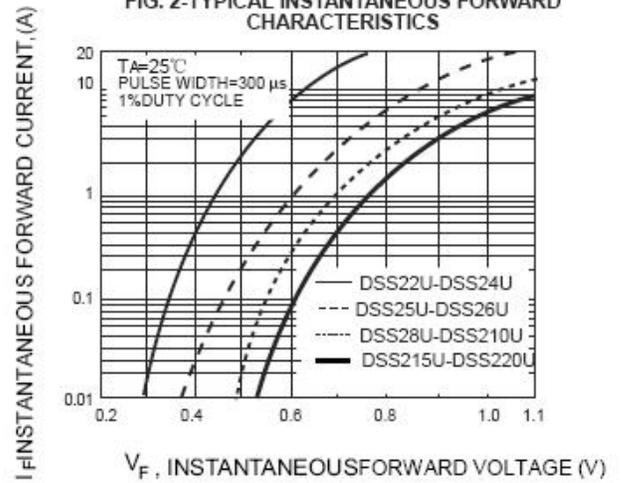


FIG. 3-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

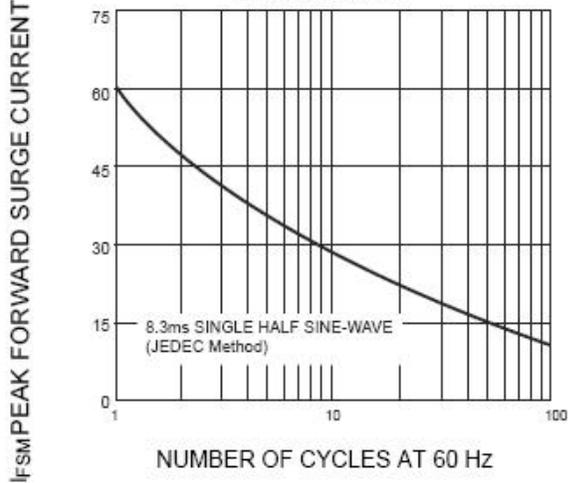
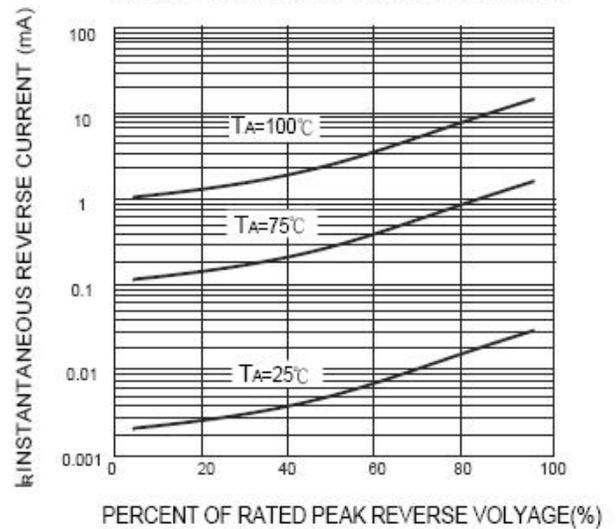
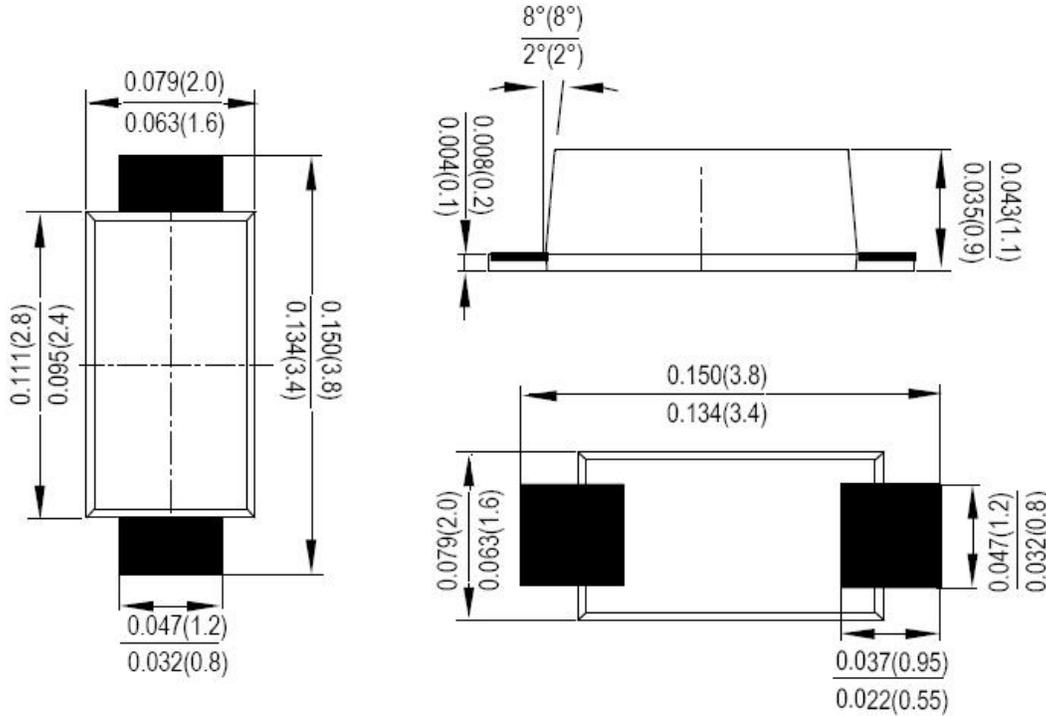


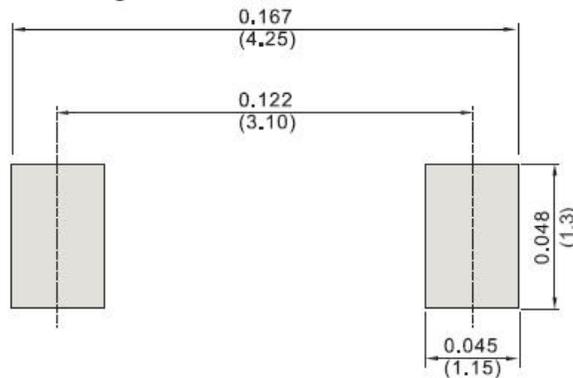
FIG. 4 TYPICAL REVERSE CHARACTERISTICS



**Mechanical Dimensions SOD-123FL(Millimeters)**



**Recommended Soldering Pattern (mm)**

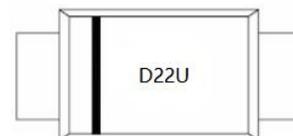


**Ordering Information**

Device	Package	Shipping
DSS22U THRU DSS220U	SOD-123FL	3000pcs / reel

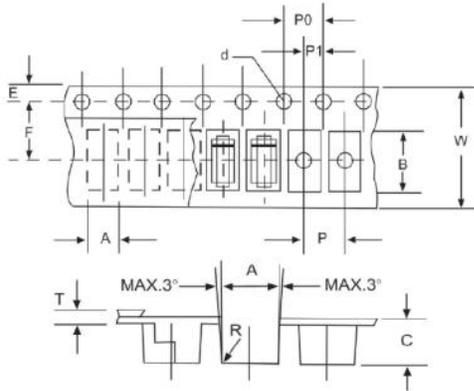
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

**Marking Diagram**



D22U = Marking Code

**Carrier Tape Specification SOD-123FL**



SYMBOL	Millimeters	
	Min.	Max.
A	1.95	2.15
B	3.85	4.05
C	1.35	1.55
d	1.50	1.60
E	1.65	1.85
F	3.40	3.60
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
W	7.90	8.30



**DSS22U  
THRU  
DSS220U**

**Technical Data  
Data Sheet N2420, Rev. -**



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